NSN 5961-01-186-3895

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-186-3895 **Inclosure Material:** Metal **Overall Length:** 1.000 inches **Overall Diameter:** 0.510 inches **Internal Configuration:** Junction contact **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 nonrepetitive peak reverse voltage, peak total value, gate terminal open-circuited **Current Rating Per Characteristic:** 30.00 amperes forward current, total rms watts **Power Rating Per Characteristic:** 40.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius case **Special Features:** Junction pattern arrangement: pnpnp **Terminal Type And Quantity:** 2 tab, solder lug and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0